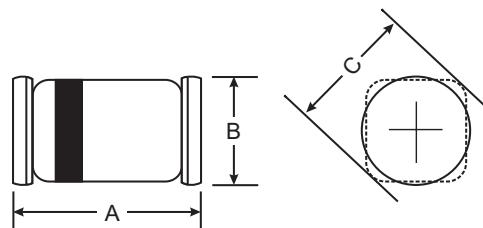


## Features

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance
- Fits on SOD323/SOT23 Footprint



## Mechanical Data

- Case: MicroMELF, Glass
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Marking: Cathode Band Only
- Weight: 0.012 grams (approx.)

MicroMELF		
Dim	Min	Max
A	1.8	2.0
B	1.20	1.25
C	1.35Ø Typical	

All Dimensions in mm

## Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	75	V
RMS Reverse Voltage	$V_{R(RMS)}$	53	V
Forward Continuous Current (Note 1)	$I_{FM}$	200	mA
Average Rectified Output Current (Note 1)	$I_O$	100	mA
Non-Repetitive Peak Forward Surge Current@ $t = 1.0\mu\text{s}$	$I_{FSM}$	2.0	A
Power Dissipation	$P_d$	500	mW
Thermal Resistance Junction to Ambient Air (Note 1)	$R_{\theta JA}$	300	K/W
Operating and Storage Temperature Range	$T_j, T_{STG}$	-65 to +175	°C

## Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Maximum Forward Voltage	$V_{FM}$	—	1.0	V	$I_F = 50\text{mA}$
Maximum Peak Reverse Current	$I_{RM}$	—	25 50 5.0	nA μA μA	$V_R = 20\text{V}$ $V_R = 20\text{V}, T_j = 150^\circ\text{C}$ $V_R = 75\text{V}$
Junction Capacitance	$C_j$	—	4.0	pF	$V_R = 0, f = 1.0\text{MHz}$
Reverse Recovery Time	$t_{rr}$	—	4.0	ns	$I_F = I_R = 10\text{mA}, V_R = 6\text{V}, R_L = 100\Omega$

Notes: 1. Valid provided that electrodes are kept at ambient temperature.

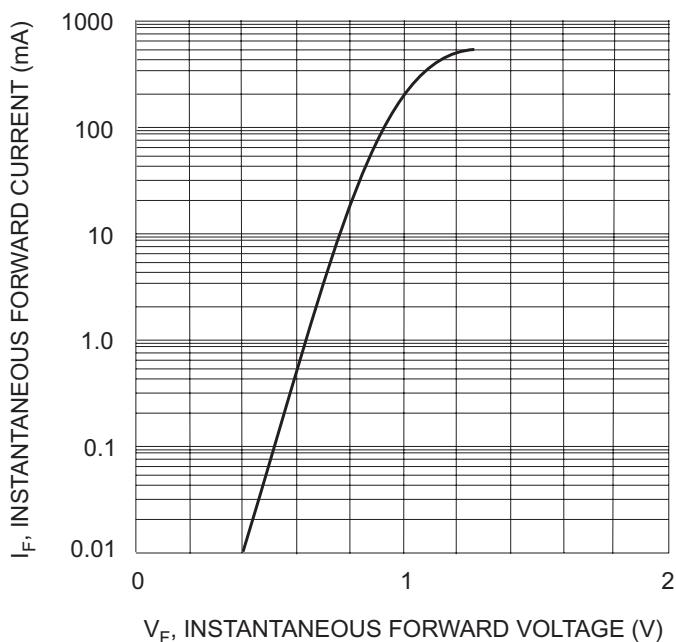


Fig. 1 Forward Characteristics

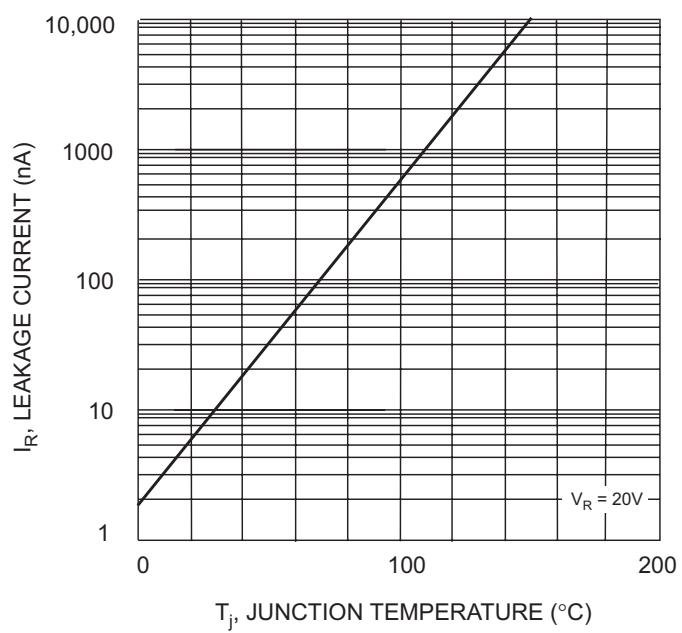


Fig. 2 Leakage Current vs Junction Temperature